

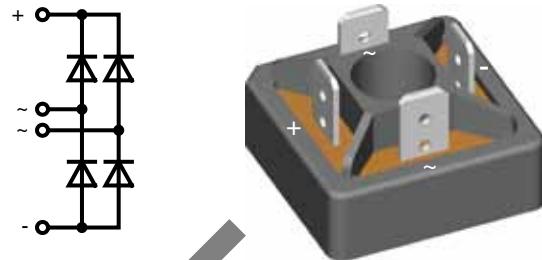
Single Phase Rectifier Bridge

Standard and Avalanche Types

$I_{dAV} = 18 \text{ A}$
 $V_{RRM} = 800-1600 \text{ V}$

V_{RSM} V	V_{BRmin} ^① V	V_{RRM} V	Standard Types	Avalanche Types
900		800	VBO 13-08N02	
1300	1230	1200	VBO 13-12N02	VBO 13-12AO2
1700	1630	1600	VBO 13-16N02	VBO 13-16AO2

① For Avalanche Types only



Symbol	Conditions	Maximum Ratings			Features
I_{dAV} ②	$T_C = 85^\circ\text{C}$, module	18	A		Avalanche rated parts available
I_{dAVM}	module	30	A		Package with DCB ceramic base plate
P_{RSM}	$T_{VJ} = T_{VJM}$	2.5	kW		Isolation voltage 3600 V~
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $V_R = 0$	220	A		Planar passivated chips
	$t = 10 \text{ ms}$ (50 Hz) $t = 8.3 \text{ ms}$ (60 Hz)	230	A		Low forward voltage drop
	$T_{VJ} = T_{VJM}$; $V_R = 0$	180	A		1/4" fast-on terminals
	$t = 10 \text{ ms}$ (50 Hz) $t = 8.3 \text{ ms}$ (60 Hz)	190	A		UL registered E 72873
I^2t	$T_{VJ} = 45^\circ\text{C}$; $V_R = 0$	240	A^2s		
	$t = 10 \text{ ms}$ (50 Hz) $t = 8.3 \text{ ms}$ (60 Hz)	220	A^2s		
	$T_{VJ} = T_{VJM}$; $V_R = 0$	160	A^2s		
	$t = 10 \text{ ms}$ (50 Hz) $t = 8.3 \text{ ms}$ (60 Hz)	150	A^2s		
T_{VJ}		-40...+150			
T_{VJM}		150			
T_{stg}		-40...+125			
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	3000	V~		
	$t = 1 \text{ min}$	3600	V~		
	$t = 1 \text{ s}$				
M_d	Mounting torque (M5) (10-32 UNF)	1.5-2	Nm		
		13-18	lb.in.		
Weight	Typ.	15	g		

Symbol	Conditions	Characteristic Values		
I_R	$V_R = V_{RRM}$	$T_{VJ} = 25^\circ\text{C}$	0.3	mA
		$T_{VJ} = T_{VJM}$	5.0	mA
V_F	$I_F = 55 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$	1.8	V
V_{TO}	For power-loss calculations only		0.85	V
r_t			17	$\text{m}\Omega$
R_{thJC}	per diode; 120° el. per module		5.60	K/W
R_{thJH}	per diode; 120° el. per module		1.40	K/W
d_s	Creeping distance on surface		6.00	K/W
d_A	Creepage distance in air ③		1.50	K/W
a	Max. allowable acceleration		13	mm
			9.5	mm
			50	m/s^2

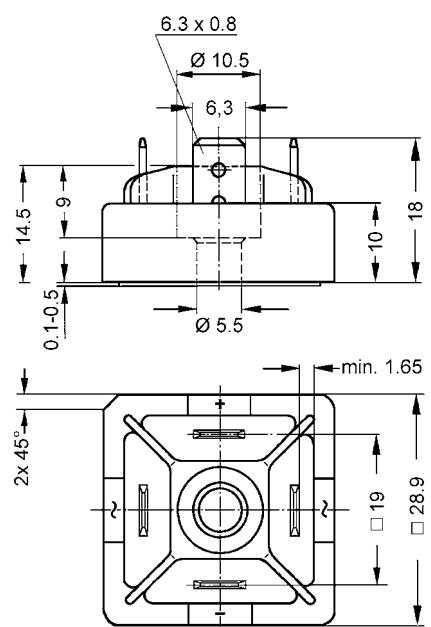
Data according to IEC 60747 and refer to a single diode unless otherwise stated.

② for resistive load at bridge output

③ with isolated fast-on tabs.

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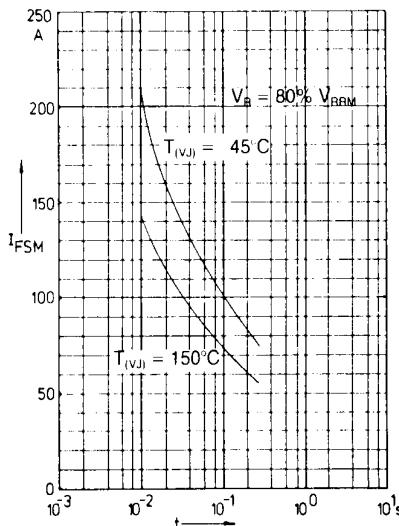


Fig. 1 Surge overload current per diode
 I_{FSM} : Crest value, t : duration

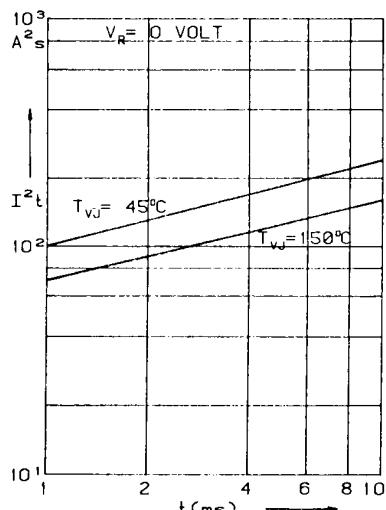


Fig. 2 I^2t versus time (1-10 ms)
 per diode

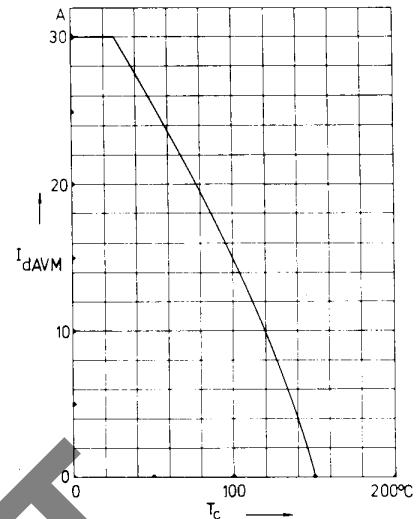


Fig. 3 Max. forward current at case temperature

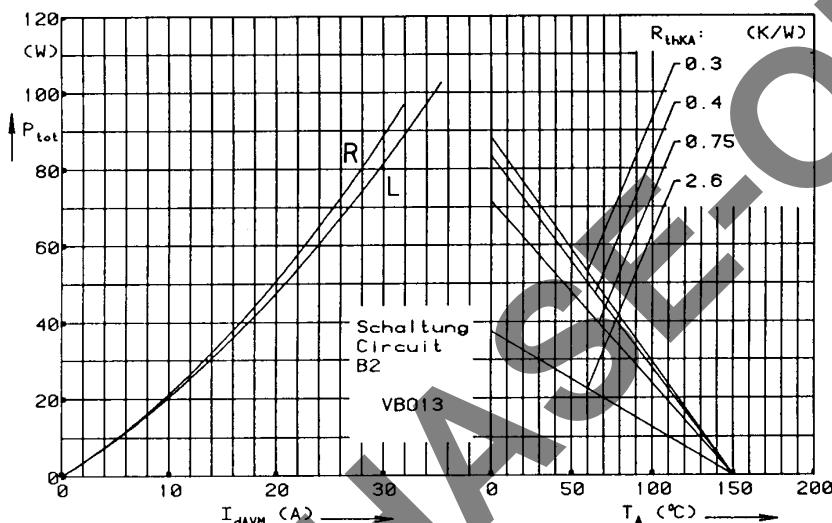


Fig. 4 Power dissipation versus direct output current and ambient temperature

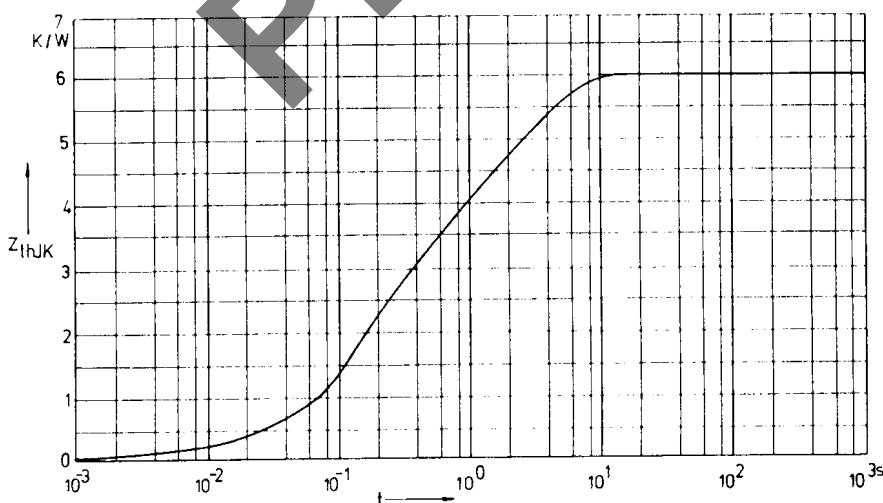


Fig. 5 Transient thermal impedance junction to heatsink per diode

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.059	0.00217
2	2.714	0.159
3	3.227	2.34

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